

SILICON DRIFT DETECTORS (SDDs)

Tailored to your requirements



FULLY CUSTOMISABLE DESIGNS

- Linear or Circular
- Planar or Focused
- Customised Unique Geometries
- Tube Length, Linear Slides, Bellows, Gate Valves etc



FOR ALL ENVIRONMENTS

- Air
- Vacuum
- UHV
- He Flush



cooling options

- Passive Air Cooling
- Close Cycle Water Cooling



PULSE PROCESSOR COMPATIBLE

 Compatible with most pulse processors available, including Quantum Detector's Xspress 3 and XIA's Flacon X.



CHANNEL OPTIONS

- 1 to >19 Channels
- Independent channels for improved serviceability and no cross talk



SENSOR OPTIONS

• Full range of window options Beryllium

AP3.3

Silicon Nitride

Carbon

Windowless

• Large range of sensor options:

Active Area	10 to 170mm²
Collimated Area	7 to 147mm²
SDD Thickness	450µm
Resolution	From 123eV Mn Ka
Peak to Background Ratio*	>15,000:1
Primary Amplification	FET, CUBE, ASIC
Cooling	Peltier Cooling

* typical values











Main Office : 5-26-22 Higashi Ooi, Shinagawa-ku, Tokyo 140-0011, Japan Phone +81-(3)4218-4700 Osaka Office : 3-18-21 Nishi nakajima, Yodogawa-ku, Oosaka 532-0011, Japan Phone +81-(6)6390-3220